

SUPER FAST RECTIFIERS

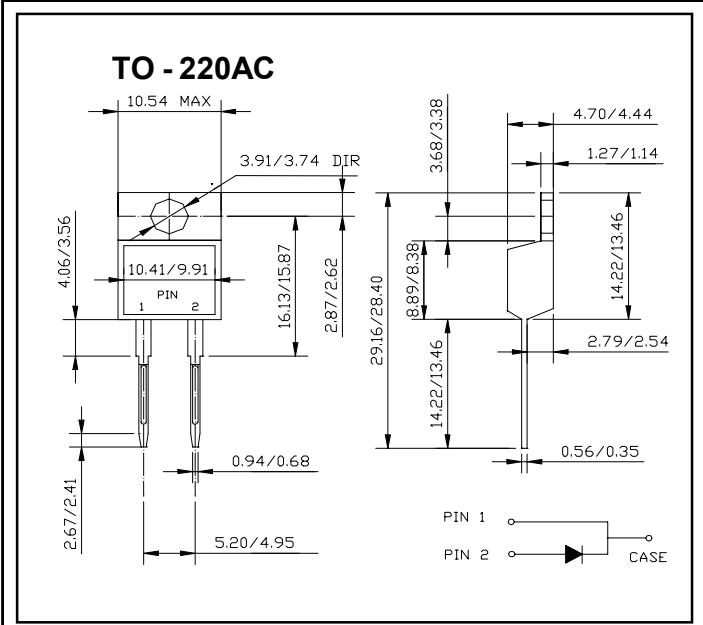
VOLTAGE RANGE: 50 --- 400 V
CURRENT: 8.0A

FEATURES

- ◇ Metal-Semiconductor junction with guard ring
- ◇ Epitaxial construction
- ◇ Low forward voltage drop, low switching losses
- ◇ High surge capability
- ◇ For use in low voltage, high frequency inverters free wheeling, and polarity protection applications
- ◇ The plastic material carries U/L recognition 94V-O

MECHANICAL DATA

- ◇ Case: JEDEC TO-220AC, molded plastic
- ◇ Terminals: Leads solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Weight: 0.078ounces, 2.24 grams
- ◇ Mounting position: Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		SF81	SF82	SF83	SF84	SF85	SF86	UNITS
Maximum recurrent peak reverse voltage	V _{RRM}	50	100	150	200	300	400	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	V
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	V
Maximum average forward rectified current @T _c =100°C	I _{F(AV)}				8.0			A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load	I _{FSM}				125			A
Maximum instantaneous forward voltage @ 8.0A	V _F			1.0		1.35		V
Maximum reverse current @T _c =25°C at rated DC blocking voltage @T _c =100°C	I _R			10				μA
500								
Typical thermal resistance (Note 2)	R _{JC}			3.0				°C/W
Maximum reverse recovery time (Note 3)	t _{rr}		35		50			ns
Typical junction capacitance (Note 1)	C _J		50		30			pF
Operating junction temperature range	T _J		- 55 ---- +150					°C
Storage temperature range	T _{STG}		-55 ---- + 150					°C

NOTE: 1. Measured at 1MHz and applied reverse voltage of 4.0 volts.

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2. Thermal resistance junction to case.

3. Reverse recovery test conditions: I_F=0.5A, I_R=1A, I_{rr}=0.25A

RATINGS AND CHARACTERISTIC CURVES

SF81 --- SF86

FIG.1 -- FORWARD CURRENT DERATING CURVE

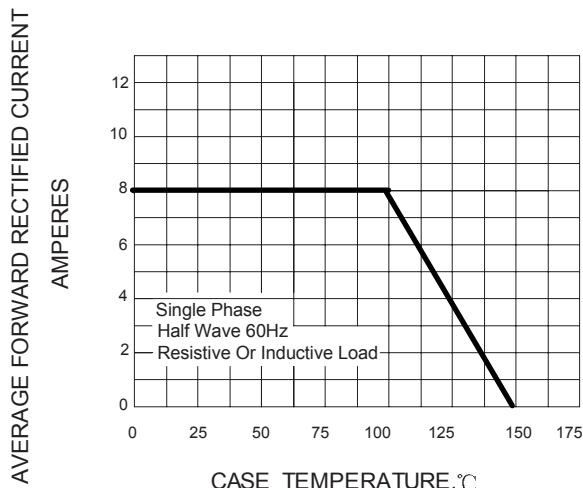


FIG.2 -- PEAK FORWARD SURGE CURRENT

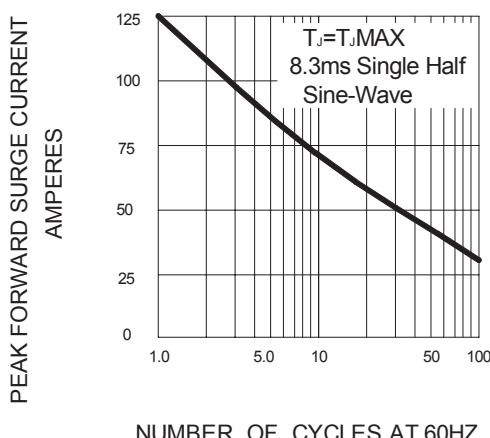


FIG.3 -- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

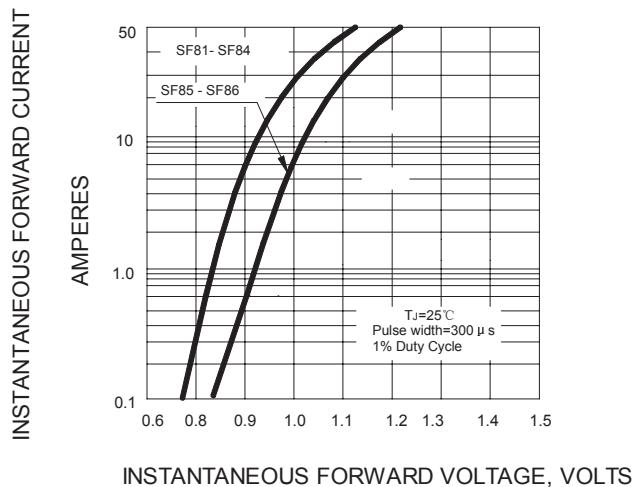


FIG.4 - TYPICAL JUNCTION CAPACITANCE

